NSN 5962-01-480-6508

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

C141 awcfs gp

Features Provided:

Ultraviolet erasable and monolithic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

22 input

Product Name:

Microcircuit, digital, memory, cmos, uv erasable-programming logic array

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

15.00 nanoseconds access

Memory Device Type:

Pal

Special Features:

This item shall be made from an unprogrammed device that is in accordance with smd specifications 5962-8753905lx

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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